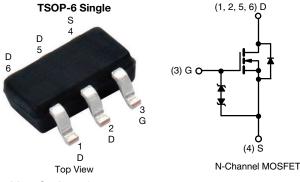


Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET

| PRODUCT SUMMARY | | | | |
|---|--------|--|--|--|
| V _{DS} (V) | 60 | | | |
| $R_{DS(on)}$ (Ω) at V_{GS} = 10 V | 0.042 | | | |
| $R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V | 0.063 | | | |
| I _D (A) | 7 | | | |
| Configuration | Single | | | |





FEATURES

- TrenchFET® power MOSFET
- Typical ESD protection 800 V HBM
- AEC-Q101 qualified
- 100 % $\rm R_g$ and UIS tested
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT HALOGEN FREE

| Marking | Code: | 8Axxx |
|---------|-------|-------|

| ORDERING INFORMATION | |
|---------------------------------|------------------|
| Package | TSOP-6 |
| Lead (Pb)-free and Halogen-free | SQ3426EEV-T1-GE3 |

| ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted) | | | | | |
|--|-------------------------|-----------------------------------|--------------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Drain-Source Voltage | | V _{DS} | 60 | V | |
| Gate-Source Voltage | | V _{GS} | ± 20 | V | |
| Continuous Drain Current | T _C = 25 °C | - I _D | 7 | | |
| | T _C = 125 °C | | 4 | | |
| Continuous Source Current (Diode Conduction) | | I _S | 6 | А | |
| Pulsed Drain Current ^a | | I _{DM} | 29 | | |
| Single Pulse Avalanche Current | L = 0.1 mH | I _{AS} | 10 | | |
| Single Pulse Avalanche Energy | | E _{AS} | 5 | mJ | |
| Maximum Power Dissipation ^a | T _C = 25 °C | D | 5 | W | |
| | T _C = 125 °C | P _D | 1.6 | | |
| Operating Junction and Storage Temperature Ran | nge | T _J , T _{stg} | - 55 to +175 | °C | |

| THERMAL RESISTANCE RATINGS | | | | | |
|----------------------------|------------------------|-------------------|-------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Junction-to-Ambient | PCB Mount ^b | R _{thJA} | 110 | °C/W | |
| Junction-to-Foot (Drain) | | R _{thJF} | 30 | 0/10 | |

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. When mounted on 1" square PCB (FR-4 material).

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| PARAMETER | SYMBOL | TES | TEST CONDITIONS | | TYP. | MAX. | UNIT | |
|---|-----------------------|--|---|-----|-------|-------|------|--|
| Static | | <u>.</u> | | | | • | • | |
| Drain-Source Breakdown Voltage | V _{DS} | $V_{GS} = 0, I_D = 250 \ \mu A$ | | 60 | - | - | V | |
| Gate-Source Threshold Voltage | V _{GS(th)} | V _{DS} = | = V _{GS} , I _D = 250 μA | 1.5 | - | 2.5 | V | |
| | | V _{DS} = | $V_{DS} = 0 V, V_{GS} = \pm 12 V$ | | - | ± 500 | nA | |
| Gate-Source Leakage | I _{GSS} | V _{DS} = | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | - | ± 1 | mA | |
| Zero Gate Voltage Drain Current | | $V_{GS} = 0 V$ | V _{DS} = 60 V | - | - | 1 | | |
| | I _{DSS} | $V_{GS} = 0 V$ | $V_{DS} = 60 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$ | - | - | 50 | μA | |
| | | $V_{GS} = 0 V$ | $V_{DS} = 60 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$ | - | - | 150 | | |
| On-State Drain Current ^a | I _{D(on)} | V _{GS} = 10 V | $V_{DS} \ge 5 V$ | 10 | - | - | Α | |
| | | V _{GS} = 10 V | I _D = 5 A | - | 0.035 | 0.042 | | |
| Drain Source On State Desistance a | Р | V _{GS} = 10 V | I _D = 5 A, T _J = 125 °C | - | 0.059 | 0.076 | Ω | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = 10 V | I _D = 5 A, T _J = 175 °C | - | 0.074 | 0.095 | | |
| | | $V_{GS} = 4.5 V$ | I _D = 4 A | - | 0.057 | 0.063 | | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} | = 15 V, I _D = 4 A | - | 12 | - | S | |
| Dynamic ^b | | | | | • | | | |
| Input Capacitance | C _{iss} | | V _{GS} = 0 V V _{DS} = 30 V, f = 1 MHz | - | 560 | 700 | pF | |
| Output Capacitance | C _{oss} | $V_{GS} = 0 V$ | | - | 85 | 105 | | |
| Reverse Transfer Capacitance | C _{rss} | | | - | 55 | 70 | | |
| Total Gate Charge ^c | Qg | | V V _{DS} = 30 V, I _D = 4 A | - | 7.6 | 12 | | |
| Gate-Source Charge ^c | Q _{gs} | V _{GS} = 4.5 V | | - | 2.1 | - | nC | |
| Gate-Drain Charge ^c | Q _{gd} | | | - | 4.1 | - | | |
| Gate Resistance | Rg | f = 1 MHz | | 1.2 | 2.4 | 3.6 | Ω | |
| Turn-On Delay Time ^c | t _{d(on)} | | | - | 9 | 14 | | |
| Rise Time ^c | t _r | $V_{DD} = 30 \text{ V}, \text{ R}_{\text{L}} = 7.5 \ \Omega$ $\text{I}_{\text{D}} \cong 4 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \ \Omega$ | | - | 12 | 18 | - ns | |
| Turn-Off Delay Time ^c | t _{d(off)} | | | - | 19 | 29 | | |
| Fall Time ^c | t _f | | | - | 7 | 11 | | |
| Source-Drain Diode Ratings and Charact | eristics ^b | | | • | • | • | • | |
| Pulsed Current ^a | I _{SM} | | | - | - | 29 | Α | |
| Forward Voltage | V _{SD} | I _F = 1.6 A, V _{GS} = 0 | | - | 0.75 | 1.2 | V | |

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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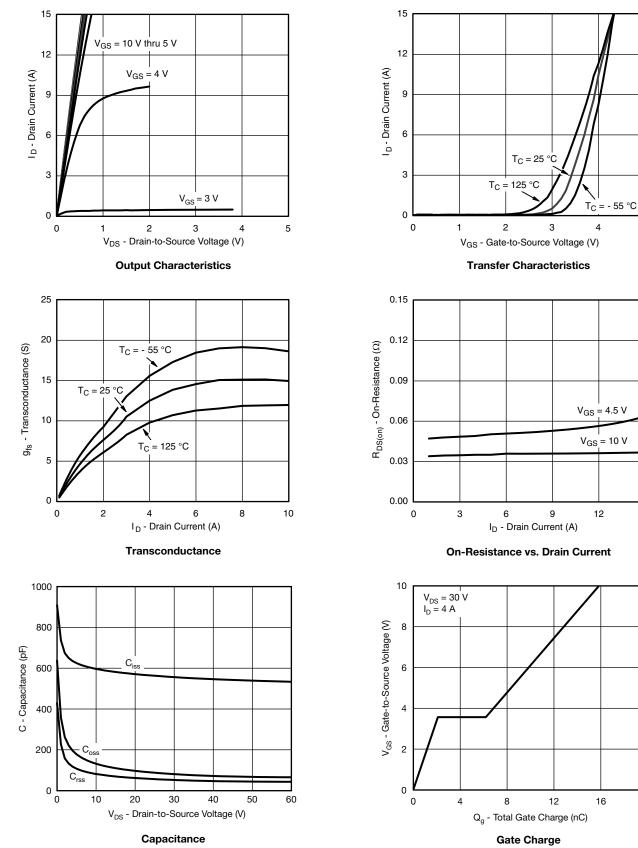
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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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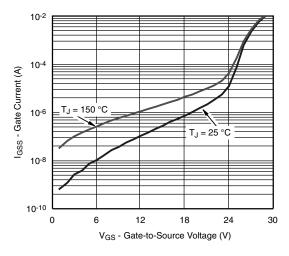
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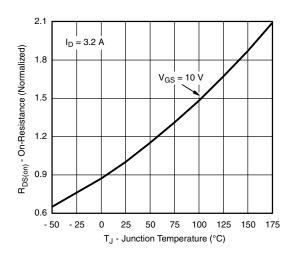


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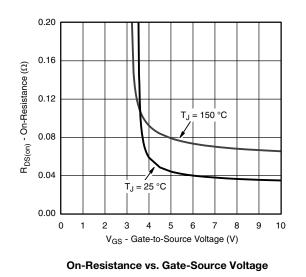
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

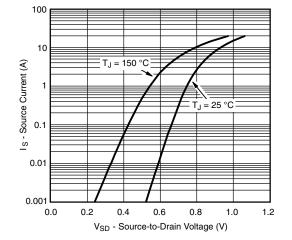


Gate Current vs. Gate-Source Voltage

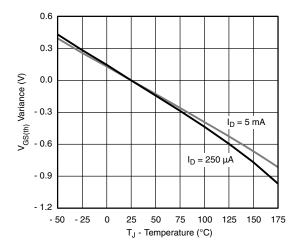


On-Resistance vs. Junction Temperature

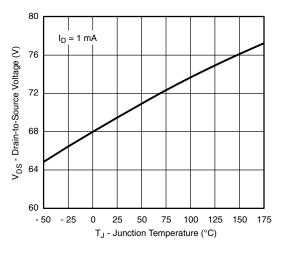




Source-Drain Diode Forward Voltage







Drain-Source Breakdown vs. Junction Temperature

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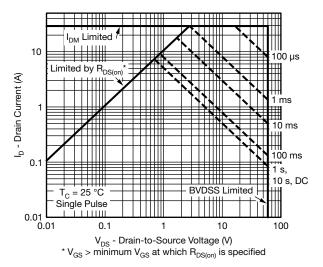
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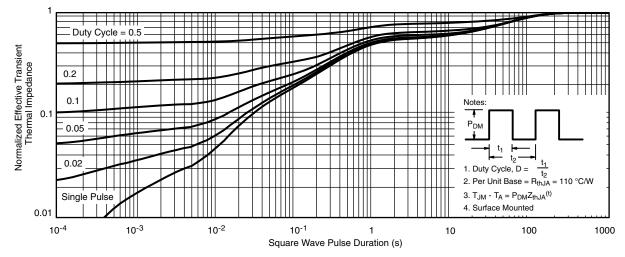


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area

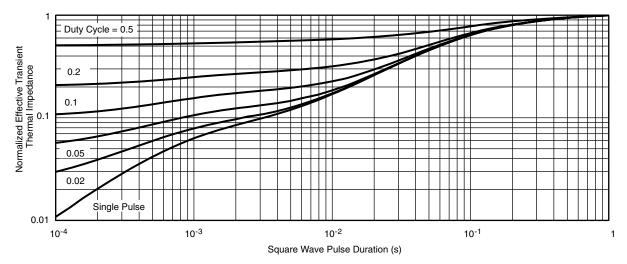


Normalized thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized thermal Transient Impedance, Junction-to-Foot

Note

• The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction to Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65351.



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